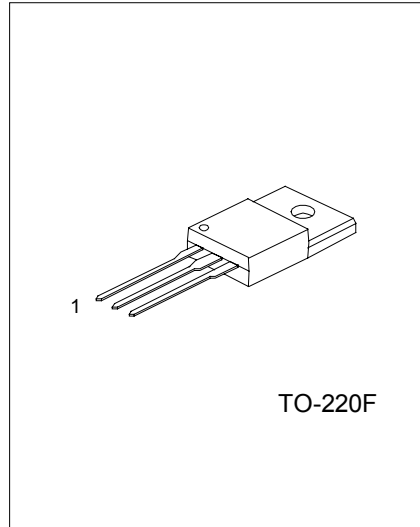
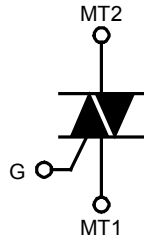


TRIACS

DESCRIPTION

Passivated triacs in a full pack plastic envelope, intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

SYMBOL



1:MT1 2:MT2 3:GATE

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT
Repetitive Peak Off State Voltage UT137FF/FG-5 UT137FF/FG-6 UT137FF/FG-8	V <sub>DRM</sub>	500* 600* 800	V
RMS On-state Current (Full sine wave, T <sub>hs</sub> ≤ 73°C)	I <sub>T(RMS)</sub>	8	A
Non-Repetitive Peak. On-State Current (Full sine wave, T <sub>j</sub> = 125°C prior to surge, with reapplied V <sub>DRM(max)</sub> ) t = 20ms t = 16.7ms	I <sub>TSM</sub>	55 60	A
I <sup>2</sup> t For Fusing (t = 10ms)	I <sup>2</sup> t	21	A <sup>2</sup> s
Repetitive Rate of Rise of On-state Current after Triggering I <sub>TM</sub> = 12A, I <sub>G</sub> = 0.2A, dI <sub>G</sub> /dt = 0.2A/μs T2+ G+ T2+ G- T2- G- T2- G+	dI <sub>T</sub> /dt	50 50 50 10	A/μs
Peak Gate Voltage	V <sub>GM</sub>	5	V
Peak Gate Current	I <sub>GM</sub>	2	A
Peak Gate Power	P <sub>GM</sub>	5	W
Average Gate Power (Over any 20ms period)	P <sub>G(AV)</sub>	0.5	W
Operating Junction Temperature	T <sub>j</sub>	125	°C
Storage Temperature	T <sub>stg</sub>	-40~150	°C

\*Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6A/μs.

ISOLATION LIMITING VALUE & CHARACTERISTIC (T<sub>HS</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Repetitive peak voltage from all three terminals to external heatsink (R.H. ≤ 65%, clean and dustfree)	V <sub>isol</sub>			1500	V
Capacitance from MT2 to external heatsink (f=1MHz)	C <sub>isol</sub>		12		pF

THERMAL RESISTANCES

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Thermal Resistance Junction to heatsink (full or half cycle) with heatsink compound without heatsink compound	R <sub>th j-hs</sub>			4.5 6.5	K/W
Thermal Resistance Junction to Ambient (In free air)	R <sub>th j-a</sub>		55		K/W

STATIC CHARACTERISTICS (T<sub>J</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX		UNIT
					UT137FF	UT137FG	
Gate trigger current	I <sub>GT</sub>	V <sub>D</sub> =12V, I <sub>T</sub> =0.1A T2+ G+ T2+ G- T2- G- T2- G+		5	25	50	mA
				8	25	50	
				11	25	50	
				30	70	100	
Latching current	I <sub>L</sub>	V <sub>D</sub> =12V, I <sub>GT</sub> =0.1A T2+ G+ T2+ G- T2- G- T2- G+		7	30	45	mA
				16	45	60	
				5	30	45	
				7	45	60	
Holding current	I <sub>H</sub>	V <sub>D</sub> = 12 V, I <sub>GT</sub> = 0.1 A		5	20	40	mA
On-state voltage	V <sub>T</sub>	I <sub>T</sub> =10A		1.3	1.65		V
Gate trigger voltage	V <sub>GT</sub>	V <sub>D</sub> =12V, I <sub>T</sub> =0.1A		0.7	1.5		V
		V <sub>D</sub> =400V, I <sub>T</sub> =0.1A, T <sub>J</sub> =125°C	0.25	0.4			V
Off-state leakage current	I <sub>D</sub>	V <sub>D</sub> =V <sub>DRM(max)</sub> , T <sub>J</sub> =125°C		0.1	0.5		mA

DYNAMIC CHARACTERISTICS (T<sub>J</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS	MIN		TYP	MAX	UNIT
			UT137FF	UT137FG			
Critical rate of rise of Off-state voltage	dV <sub>D</sub> /dt	V <sub>DM</sub> = 67% V <sub>DRM(max)</sub> ; T <sub>J</sub> = 125°C; exponential waveform; gate open circuit	50	200	250		V/μs
Critical rate of change of Commutating voltage	dV <sub>com</sub> /dt	V <sub>DM</sub> =400V; T <sub>J</sub> =95°C; I <sub>T(RMS)</sub> =8A; dI <sub>com</sub> /dt = 3.6A/ms; gate open circuit		10	20		V/μs
Gate controlled turn-on time	t <sub>gt</sub>	I <sub>TM</sub> = 12 A; V <sub>D</sub> = V <sub>DRM(max)</sub> ; I <sub>G</sub> =0.1A; dI <sub>G</sub> /dt=5A/μs			2		μs

TYPICAL CHARACTERISTICS

Figure 1. Maximum on-state Dissipation,  $P_{tot}$  vs RMS On-state Current,  $I_T(RMS)$ , Where  $\alpha$  = Conduction Angle.

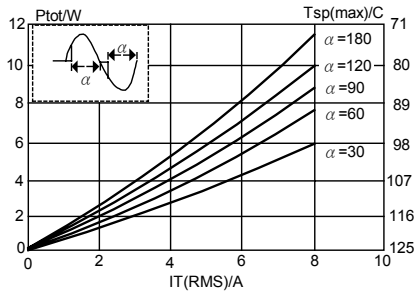


Figure 4. Maximum Permissible RMS Current  $I_T(RMS)$  vs Heatsink Temperature  $T_{hs}$

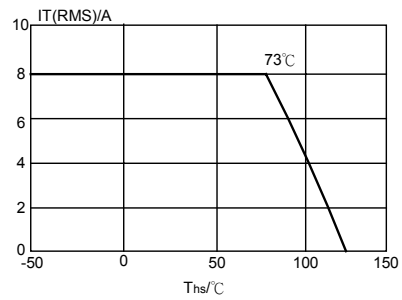


Figure 2. Maximum Permissible Non-repetitive Peak On-state Current  $I_{TSM}$ , vs Pulse Width  $t_p$ , for Sinusoidal Currents,  $t_p \leq 20ms$

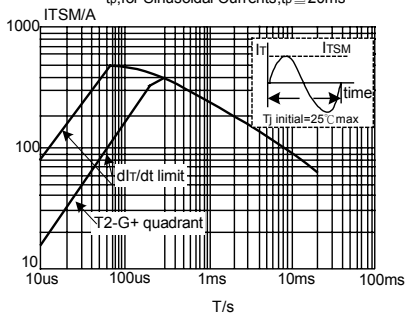


Figure 5. Maximum Permissible Repetitive RMS on-state Current  $I_T(RMS)$ , vs Surge Duration, for Sinusoidal Currents,  $f=50Hz$ ,  $T_{hs} \leq 73^\circ C$

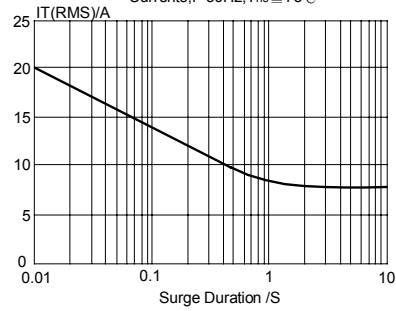


Figure 3. Maximum Permissible Non-Repetitive peak on-state Current  $I_{TSM}$ , vs Number of Cycles, for Sinusoidal Currents,  $f=50Hz$

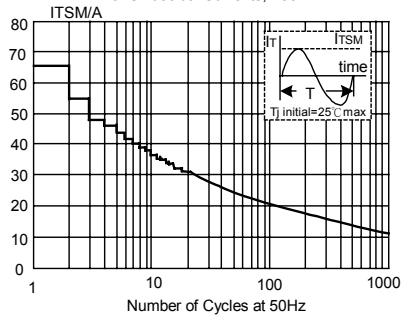


Figure 6. Normalised Gate Trigger Voltage  $V_{GT}(T_j) / V_{GT}(25^\circ C)$ , vs Junction Temperature  $T_j$

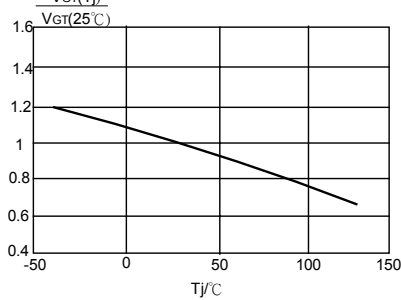


Figure 7. Normalised Gate Trigger Current  $I_{GT}(T_j)/I_{GT}(25^\circ\text{C})$ , vs Junction Temperature  $T_j$

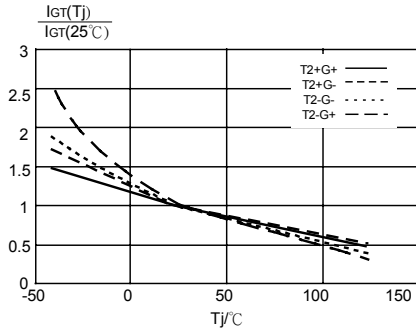


Figure 8. Normalised Latching Current  $I_L(T_j)/I_L(25^\circ\text{C})$ , vs Junction Temperature  $T_j$

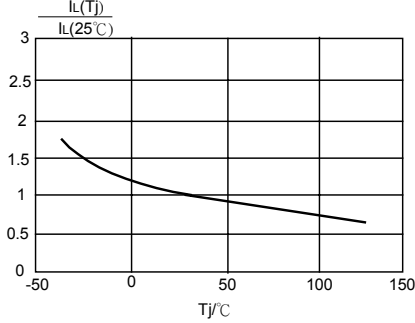


Figure 9. Normalised Holding Current  $I_H(T_j)/I_H(25^\circ\text{C})$ , vs Junction Temperature  $T_j$

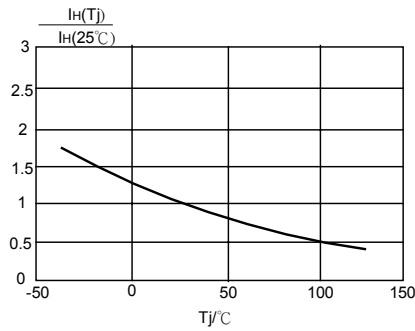


Figure 10. Typical and Maximum On-state Characteristic

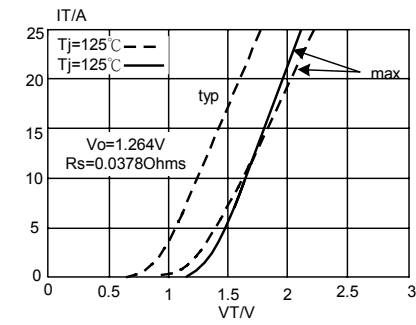


Figure 11. Transient Thermal Impedance  $Z_{th\ j-hs}$ , vs Pulse Width  $t_p$

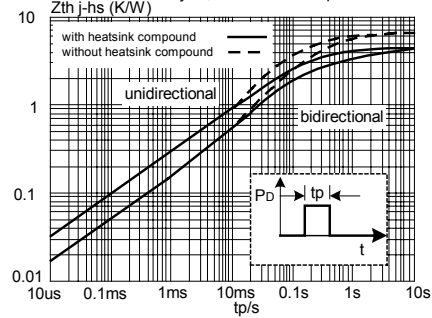
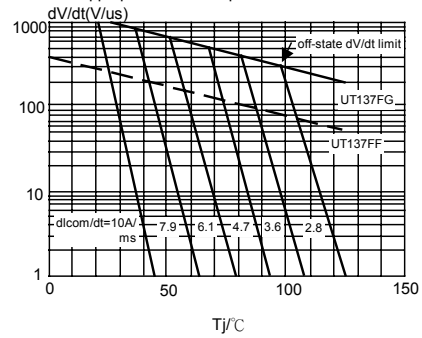


Figure 12. Typical commutation  $dV/dt$  vs junction temperature, parameter commutation  $dI/dt$ . The triac should commute when the  $dV/dt$  is below the value on the appropriate curve for pre-commutation  $dI/dt$



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